GP1S39

■ Features

1. Ultra-compact package

2. PWB mounting type

3. Double-phase phototransistor output type for detecting of rotation direction and count

4. Wide gap between light emitter and

detector: 1.5mm 5. Slit width: 0.8mm 6. Detecting pitch: 0.6mm

■ Applications

1. Mouses

2. Cameras

■ Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

	Parameter	Symbol	Rating	Unit	
	Forward current	I_F	50	mA	
Input	Reverse voltage	VR	6	V	
	Power dissipation	P	75	mW	
Output	Collector amittar valtage	V_{CE_1O}	35	V	
	Collector-emitter voltage	V _{CE2} O	33	V	
	Emitter-collector voltage	V_{E_1CO}	6	V	
	Ellitter-collector voltage	V_{E_2CO}	U	V	
	Collector current	Ic	20	mA	
	Collector power dissipation	Pc	75	mW	
	Total power dissipation	P tot	100	mW	
	Operating temperature	Topr	- 25 to + 85	°C	
	Storage temperature	Tstg	- 40 to + 100	°C	
	*1Soldering temperature	T_{sol}	260	°C	

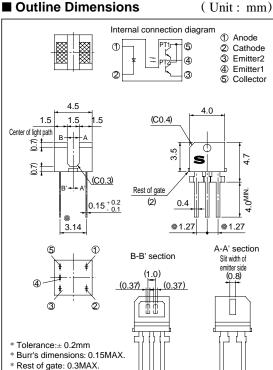
^{*1} For 5 seconds

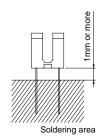
Subminiature, Double-phase **Output, Wide Gap Photointerrupter**

■ Outline Dimensions

* (): Reference dimensions * The dimensions indicated by # refer to those measured from the lead base.

resin marked





* Internal elements are appeared because of thin external mold

■ Electro-optical Characteristics

 $(Ta = 25^{\circ}C)$

Parameter		Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Forward voltage		VF	$I_F = 20 mA$	-	1.2	1.4	V
Reverse current		I_R	$V_R = 3V$	-	-	10	μΑ
Collector dark current		I_{CEO}	$V_{\text{CE}} = 20V$	-	-	100	nA
Collector current		I_{C}	$V_{CE} = 5V$, $I_F = 4mA$	130	-	520	μΑ
Collector current ratio		I_{C1}/I_{C2}	$V_{CE} = 5V$, $I_F = 4mA$	0.67	-	1.5	-
Collector-emitter saturation voltage		V _{CE(sat)}	$I_F=8mA,I_C=50~\mu$ A	-	-	0.4	V
Response time	Rise time	t _r	$V_{ CE} = 5 V, I_{ C} = 100 \; \mu \; A$	-	50	150	μs
	Fall time	t_{f}	$R_{\rm L}=1000\Omega$	-	50	150	μs
	Forward voltage Reverse current Collector dark current Collector current Collector current ratio Collector-emitter saturatio	Forward voltage Reverse current Collector dark current Collector current Collector current ratio Collector-emitter saturation voltage Response time	Forward voltage V_F Reverse current I_R Collector dark current I_{CEO} Collector current I_C Collector current ratio $I_{C1/I_{C2}}$ Collector-emitter saturation voltage $V_{CE(sat)}$ Response time I_C	Forward voltage V_F $I_F = 20mA$ Reverse current I_R $V_R = 3V$ Collector dark current I_{CEO} $V_{CE} = 20V$ Collector current I_C $V_{CE} = 5V, I_F = 4mA$ Collector current ratio I_{C1}/I_{C2} $V_{CE} = 5V, I_F = 4mA$ Collector-emitter saturation voltage $V_{CE(sat)}$ $I_F = 8mA, I_C = 50 \mu A$ Response time I_C I	Forward voltage $ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	Forward voltage $ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$

Fig. 1 Forward Current vs. Ambient Temperature

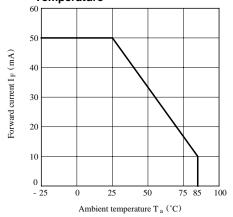


Fig. 3 Forward Current vs. Forward Voltage

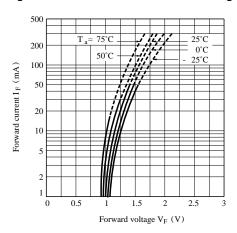


Fig. 2 Power Dissipation vs. Ambient Temperature

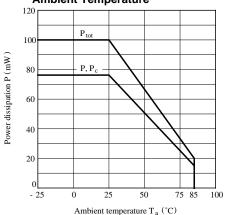
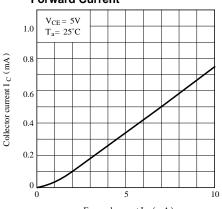


Fig. 4 Collector Current vs.
Forward Current



Forward current I $_F$ (mA)



Fig. 5 Collector Current vs.
Collector-emitter Voltage

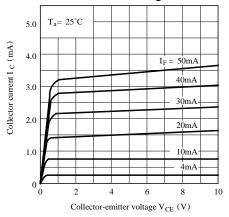


Fig. 7 Collector-emitter Saturation Voltage vs. Ambient Temperature

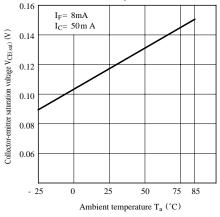


Fig. 9 Response Time vs. Load Resistance

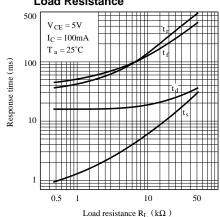


Fig. 6 Collector Current vs.
Ambient Temperature

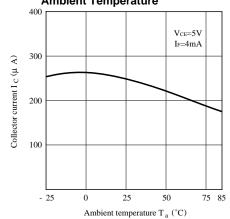
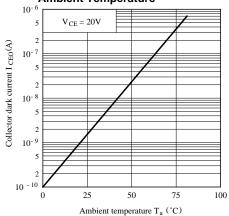


Fig. 8 Collector Dark Current vs.
Ambient Temperature



Test Circuit for Response Time

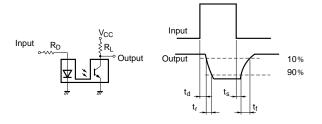


Fig.10 Relative Collector Current vs. Shield Distance (1)

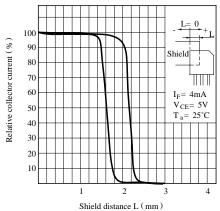
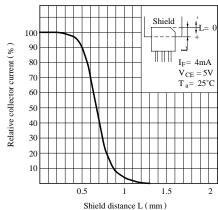


Fig.11 Relative Collector Current vs. Shield Distance (2)



• Please refer to the chapter "Precautions for Use".

NOTICE

- •The circuit application examples in this publication are provided to explain representative applications of SHARP devices and are not intended to guarantee any circuit design or license any intellectual property rights. SHARP takes no responsibility for any problems related to any intellectual property right of a third party resulting from the use of SHARP's devices.
- •Contact SHARP in order to obtain the latest device specification sheets before using any SHARP device. SHARP reserves the right to make changes in the specifications, characteristics, data, materials, structure, and other contents described herein at any time without notice in order to improve design or reliability. Manufacturing locations are also subject to change without notice.
- Observe the following points when using any devices in this publication. SHARP takes no responsibility for damage caused by improper use of the devices which does not meet the conditions and absolute maximum ratings to be used specified in the relevant specification sheet nor meet the following conditions:
 - (i) The devices in this publication are designed for use in general electronic equipment designs such as:
 - Personal computers
 - Office automation equipment
 - Telecommunication equipment [terminal]
 - Test and measurement equipment
 - Industrial control
 - Audio visual equipment
 - Consumer electronics
 - (ii) Measures such as fail-safe function and redundant design should be taken to ensure reliability and safety when SHARP devices are used for or in connection with equipment that requires higher reliability such as:
 - Transportation control and safety equipment (i.e., aircraft, trains, automobiles, etc.)
 - Traffic signals
 - Gas leakage sensor breakers
 - Alarm equipment
 - Various safety devices, etc.
 - (iii) SHARP devices shall not be used for or in connection with equipment that requires an extremely high level of reliability and safety such as:
 - Space applications
 - Telecommunication equipment [trunk lines]
 - Nuclear power control equipment
 - Medical and other life support equipment (e.g., scuba).
- •Contact a SHARP representative in advance when intending to use SHARP devices for any "specific" applications other than those recommended by SHARP or when it is unclear which category mentioned above controls the intended use.
- •If the SHARP devices listed in this publication fall within the scope of strategic products described in the Foreign Exchange and Foreign Trade Control Law of Japan, it is necessary to obtain approval to export such SHARP devices.
- •This publication is the proprietary product of SHARP and is copyrighted, with all rights reserved. Under the copyright laws, no part of this publication may be reproduced or transmitted in any form or by any means, electronic or mechanical, for any purpose, in whole or in part, without the express written permission of SHARP. Express written permission is also required before any use of this publication may be made by a third party.
- Contact and consult with a SHARP representative if there are any questions about the contents of this
 publication.